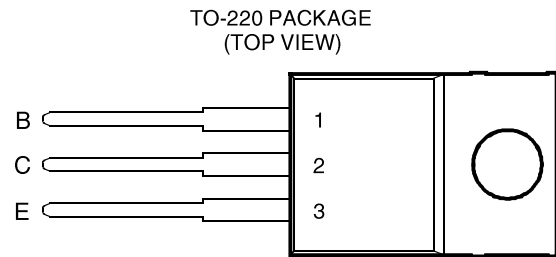


- **Designed for Complementary Use with TIP130, TIP131 and TIP132**
- **70 W at 25°C Case Temperature**
- **8 A Continuous Collector Current**
- **Minimum  $h_{FE}$  of 1000 at 4 V, 4 A**



Pin 2 is in electrical contact with the mounting base.

absolute maximum ratings **at 25°C case temperature (unless otherwise noted)**

RATING		SYMBOL	VALUE	UNIT
Collector-base voltage ( $I_E = 0$ )	TIP135	$V_{CBO}$	-60	V
	TIP136		-80	
	TIP137		-100	
Collector-emitter voltage ( $I_B = 0$ )	TIP135	$V_{CEO}$	-60	V
	TIP136		-80	
	TIP137		-100	
Emitter-base voltage		$V_{EBO}$	-5	V
Continuous collector current		$I_C$	-8	A
Peak collector current (see Note 1)		$I_{CM}$	-12	A
Continuous base current		$I_B$	-0.3	A
Continuous device dissipation at (or below) 25°C case temperature (see Note 2)		$P_{tot}$	70	W
Continuous device dissipation at (or below) 25°C free air temperature (see Note 3)		$P_{tot}$	2	W
Unclamped inductive load energy (see Note 4)		$\frac{1}{2}LI_C^2$	75	mJ
Operating junction temperature range		$T_j$	-65 to +150	°C
Storage temperature range		$T_{stg}$	-65 to +150	°C
Lead temperature 3.2 mm from case for 10 seconds		$T_L$	260	°C

- NOTES: 1. This value applies for  $t_p \leq 0.3$  ms, duty cycle  $\leq 10\%$ .  
 2. Derate linearly to 150°C case temperature at the rate of 0.56 W/°C.  
 3. Derate linearly to 150°C free air temperature at the rate of 16 mW/°C.  
 4. This rating is based on the capability of the transistor to operate safely in a circuit of:  $L = 20$  mH,  $I_{B(on)} = -5$  mA,  $R_{BE} = 100 \Omega$ ,  $V_{BE(off)} = 0$ ,  $R_S = 0.1 \Omega$ ,  $V_{CC} = -20$  V.

# TIP135, TIP136, TIP137

## PNP SILICON POWER DARLINGTONS

### electrical characteristics at 25°C case temperature

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$	Collector-emitter breakdown voltage	$I_C = -30 \text{ mA}$	$I_B = 0$	(see Note 5)	TIP135 TIP136 TIP137	-60 -80 -100		V
$I_{CEO}$	Collector-emitter cut-off current	$V_{CE} = -30 \text{ V}$ $V_{CE} = -40 \text{ V}$ $V_{CE} = -50 \text{ V}$	$I_B = 0$ $I_B = 0$ $I_B = 0$		TIP135 TIP136 TIP137		-0.5 -0.5 -0.5	mA
$I_{CBO}$	Collector cut-off current	$V_{CB} = -60 \text{ V}$ $V_{CB} = -80 \text{ V}$ $V_{CB} = -100 \text{ V}$ $V_{CB} = -60 \text{ V}$ $V_{CB} = -80 \text{ V}$ $V_{CB} = -100 \text{ V}$	$I_E = 0$ $I_E = 0$ $I_E = 0$ $I_E = 0$ $I_E = 0$ $I_E = 0$	$T_C = 100^\circ\text{C}$ $T_C = 100^\circ\text{C}$ $T_C = 100^\circ\text{C}$	TIP135 TIP136 TIP137 TIP135 TIP136 TIP137		-0.2 -0.2 -0.2 -1 -1 -1	mA
$I_{EBO}$	Emitter cut-off current	$V_{EB} = -5 \text{ V}$	$I_C = 0$				-5	mA
$h_{FE}$	Forward current transfer ratio	$V_{CE} = -4 \text{ V}$ $V_{CE} = -4 \text{ V}$	$I_C = -1 \text{ A}$ $I_C = -4 \text{ A}$	(see Notes 5 and 6)		500 1000	15000	
$V_{CE(sat)}$	Collector-emitter saturation voltage	$I_B = -16 \text{ mA}$ $I_B = -30 \text{ mA}$	$I_C = -4 \text{ A}$ $I_C = -6 \text{ A}$	(see Notes 5 and 6)			-2 -3	V
$V_{BE}$	Base-emitter voltage	$V_{CE} = -4 \text{ V}$	$I_C = -4 \text{ A}$	(see Notes 5 and 6)			-2.5	V
$C_{obo}$	Output capacitance	$V_{CB} = -10 \text{ V}$	$I_E = 0$				200	pF
$V_{EC}$	Parallel diode forward voltage	$I_E = -8 \text{ A}$	$I_B = 0$	(see Notes 5 and 6)			-3.5	V

NOTES: 5. These parameters must be measured using pulse techniques,  $t_p = 300 \mu\text{s}$ , duty cycle  $\leq 2\%$ .

6. These parameters must be measured using voltage-sensing contacts, separate from the current carrying contacts.

### thermal characteristics

PARAMETER		MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to case thermal resistance			1.78	$^\circ\text{C/W}$
$R_{\theta JA}$	Junction to free air thermal resistance			62.5	$^\circ\text{C/W}$

TYPICAL CHARACTERISTICS

TYPICAL DC CURRENT GAIN  
vs  
COLLECTOR CURRENT

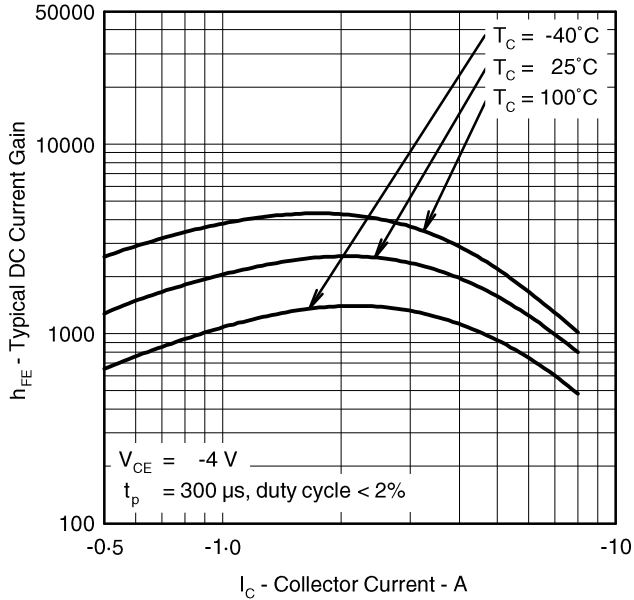


Figure 1.

COLLECTOR-EMITTER SATURATION VOLTAGE  
vs  
COLLECTOR CURRENT

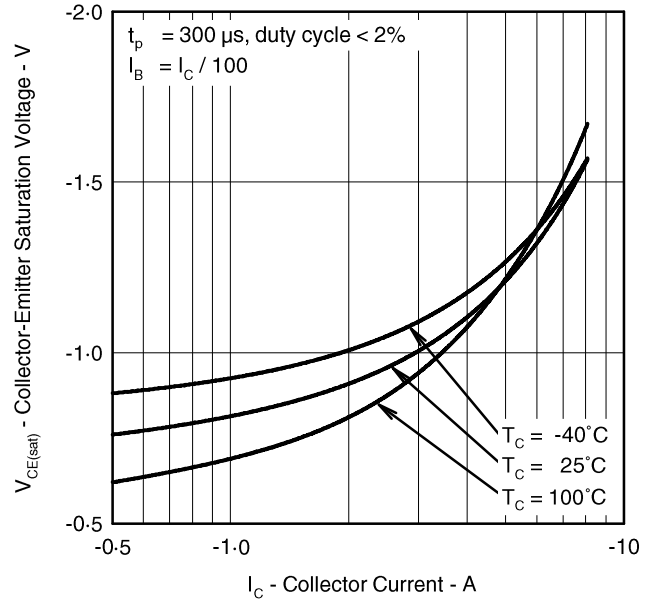


Figure 2.

BASE-EMITTER SATURATION VOLTAGE  
vs  
COLLECTOR CURRENT

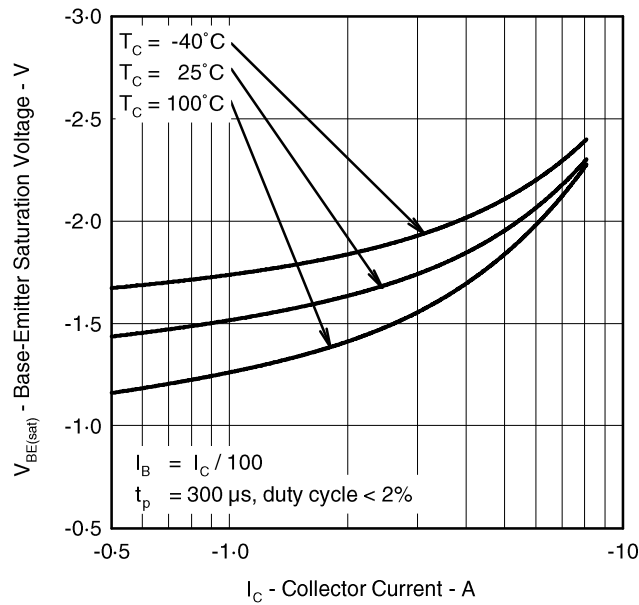


Figure 3.

# TIP135, TIP136, TIP137 PNP SILICON POWER DARLINGTONS

## MAXIMUM SAFE OPERATING REGIONS

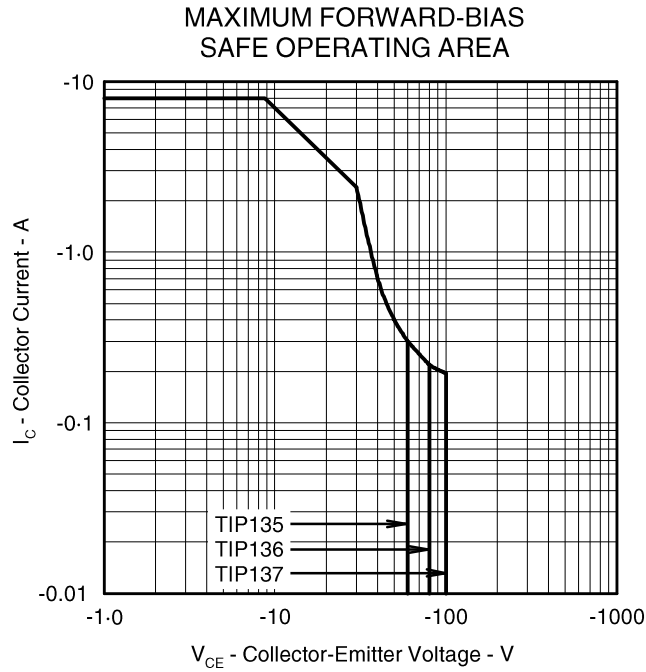


Figure 4.

## THERMAL INFORMATION

### MAXIMUM POWER DISSIPATION vs CASE TEMPERATURE

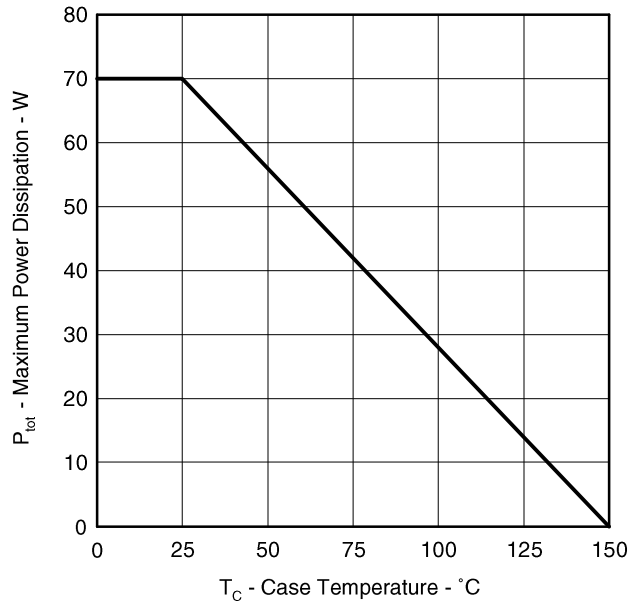


Figure 5.

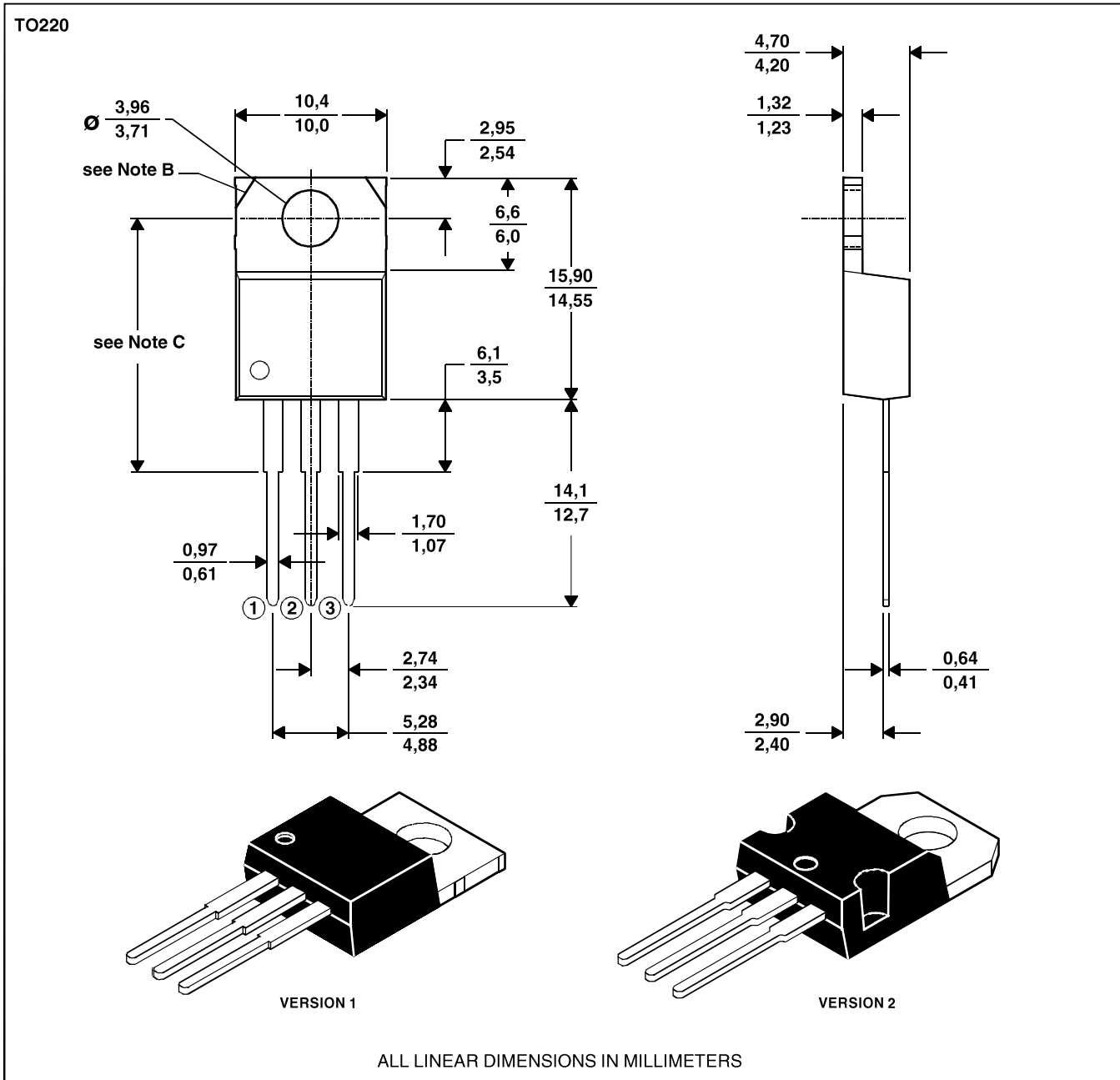
**TIP135, TIP136, TIP137**  
**PNP SILICON POWER DARLINGTONS**

**MECHANICAL DATA**

**TO-220**

**3-pin plastic flange-mount package**

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



- NOTES: A. The centre pin is in electrical contact with the mounting tab.  
 B. Mounting tab corner profile according to package version.  
 C. Typical fixing hole centre stand off height according to package version.  
 Version 1, 18.0 mm. Version 2, 17.6 mm.